

ON Semiconductor®

FDP5500-F085

N-Channel UltraFET Power MOSFET

55V, 80A, 7mΩ

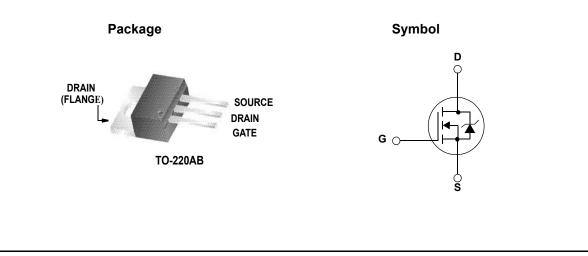
Features

- Typ $r_{DS(on)}$ = 5.1m Ω at V_{GS} = 10V, I_D = 80A
- Typ $Q_{g(10)}$ = 114nC at V_{GS} = 10V
- Simulation Models
- -Temperature Compensated PSPICE and SABERTM Models
- Peak Current vs Pulse Width Curve
- UIS Rating Curve
- Qualified to AEC Q101
- RoHS Compliant

Applications

- DC Linear Mode Control
- Solenoid and Motor Control
- Switching Regulators
- Automotive Systems





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Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage	(Note 1)	55	V
V _{DGR}	Drain to Gate Voltage (R_{GS} = 20k Ω)	(Note 1)	55	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 135 ^o C, V _{GS} = 10V)		80	Α
D	Pulsed		See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	860	mJ
П	Power Dissipation		375	W
P _D	Derate above 25°C		2.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	
ΤL	Max. Lead Temp. for Soldering (at 1.6mm from case for 10sec)		300	°C
T _{pkg}	Max. Package Temp. for Soldering (Package Body for 10sec)		260	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.4	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient TO-220AB, 1in ² copper pad area	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP5500	FDP5500-F085	TO-220AB	Tube	N/A	50 units

Electrical Characteristics T_{C} = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
	restariation					

Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0\	/	55	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 50V, V_{GS} = 0^{10}$	V	-	-	1	
DSS	Zero Gale Vollage Drain Current	V _{DS} = 45V	$T_{C} = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2	2.8	4	V
r _{DS(on)}	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V	-	5.1	7	mΩ

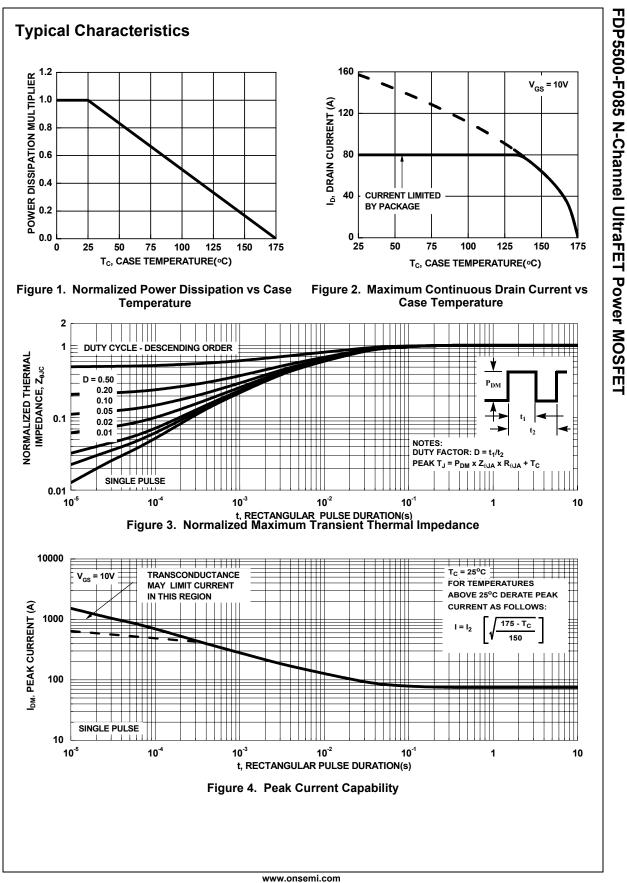
Dynamic Characteristics

C _{iss}	Input Capacitance		0) (-	3565	-	pF
C _{oss}	Output Capacitance	V _{DS} = 25V, V _{GS} = f = 1MHz	UV,	-	1310	-	pF
C _{rss}	Reverse Transfer Capacitance			-	395	-	pF
Q _{g(TOT)}	Total Gate Charge at 20V	V _{GS} = 0 to 20V		-	207	269	nC
Q _{g(10)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	$V_{DD} = 30V$	-	114	148	nC
Q _{g(TH)}	Threshold Gate Charge	V_{GS} = 0 to 2V	$I_D = 80A$ $R_1 = 0.4\Omega$	-	6.6	8.6	nC
Q _{gs}	Gate to Source Gate Charge		$R_{L} = 0.452$ $I_{g} = 1.0 \text{mA}$	-	17.2	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		9	-	52	-	nC

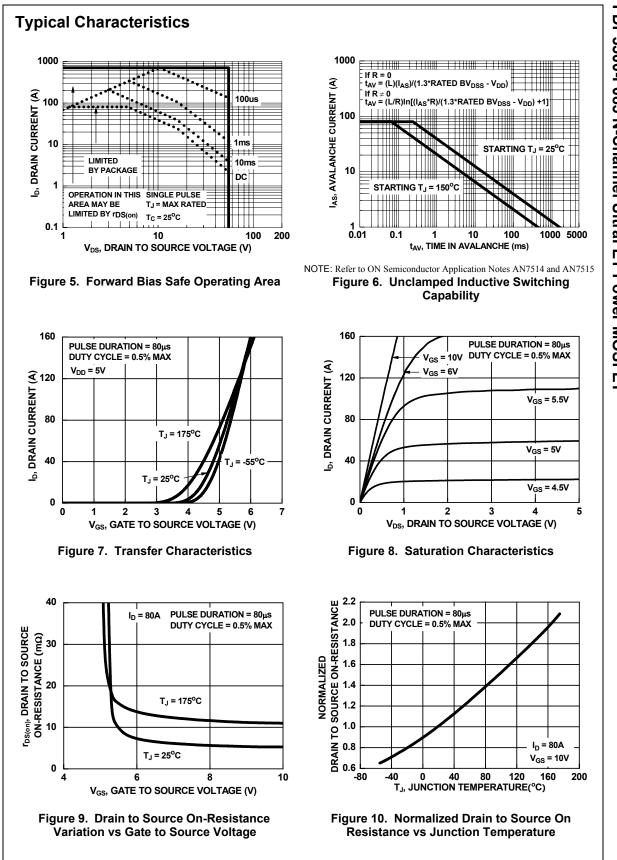
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{on}	Turn-On Time	V_{DD} = 30V, I _D = 80A, R_L = 0.4Ω, V _{GS} = 10V, R_{GS} = 2.5Ω	-	-	75	ns
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time		-	34	-	ns
t _{d(off)}	Turn-Off Delay Time		-	37	-	ns
t _f	Fall Time		-	23	-	ns
t _{off}	Turn-Off Time		-	-	96	ns
Drain-So V _{SD}	ource Diode Characteristics	I _{SD} = 80A	-	0.9	1.25	V
t _{rr}	Reverse Recovery Time		-	58	75	ns
Q _{rr}	Reverse Recovery Charge	I _F = 80A, dI _{SD} /dt = 100A/μs	_	71	92	nC

Notes:

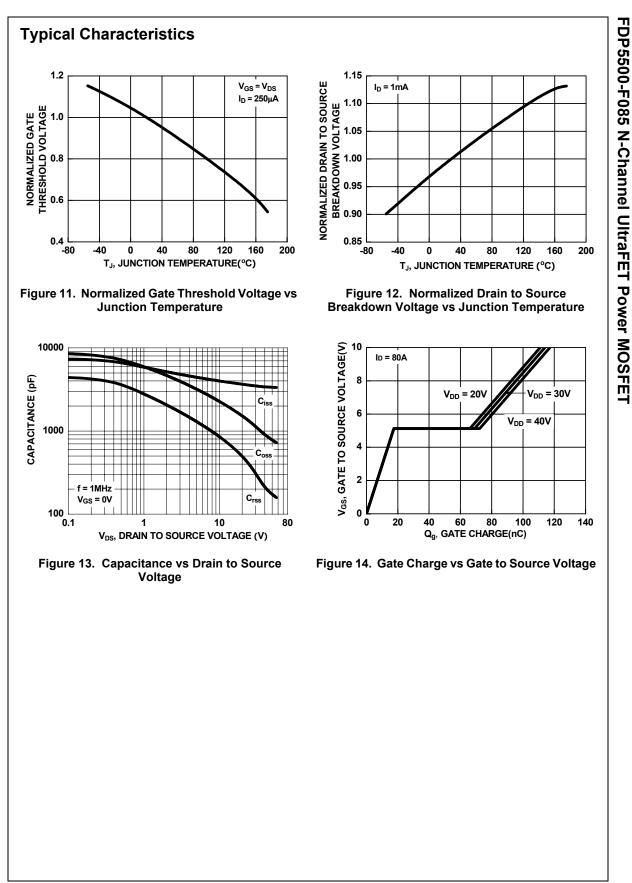
1: Starting $T_J = 25^{\circ}C \text{ to}175^{\circ}C.$ 2: Starting $T_J = 25^{\circ}C, L = 0.42\text{mH}, I_{AS} = 64\text{A}$



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FDP5500-F085 N-Channel UltraFET Power MOSFET



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